

# BEAMR2-BEAMMAP2

Scanning Slits Beam Profilers

## KEY FEATURES



- 1 Plug and Play**  
Direct USB2.0 connection
- 2 Beam'R2**  
Each single plane XY beam profiling head contains a 2.5  $\mu\text{m}$  slit pair for high dynamic range slit mode & a 25  $\mu\text{m}$  slit pair for 0.1  $\mu\text{m}$  resolution Knife-Edge mode
- 3 BeamMap2**  
Adds multiple Z-plane scanning to allow the measurement of:
  - Real-time XYZ profiles, Focus position
  - Real-time M2, Divergence, Collimation
- 4 Dual Sensors**  
Each model is available with dual sensors, for the largest wavelength range possible:
  - DD-2.0: Si + InGaAs
  - DD-2.4: Si + Extended InGaAs
- 5 True2D Slits**  
0.4  $\mu\text{m}$  thick metallic multilayer films on a sapphire substrate avoid the tunnel effect of air slits

## AVAILABLE MODELS



Beam'R2  
Single Sensor



BeamMap2  
Dual Sensors



Beam'R2-DD  
Single Sensor



BeamMap2-DD  
Dual Sensors

## AVAILABLE SENSORS

- Single Sensor:**
- Si 190 - 1000 nm
  - InGaAs 650 - 1800 nm
- Dual Sensors:**
- Si + InGaAs 190 - 1800 nm
  - Si + Ext. InGaAs 190 - 2500 nm

## ACCESSORIES



Stand with Delrin Post  
(Model Number: 200428)



CUB, CUB-UV & EAM-2  
Beam Splitters and Attenuators



Pelican Carrying Case

## SEE ALSO

ACCESSORIES FOR BEAM DIAGNOSTICS  
LIST OF ALL ACCESSORIES

184  
186

MONITORS  
ENERGY DETECTORS  
POWER DETECTORS  
HIGH POWER DETECTORS  
PHOTO DETECTORS  
THZ DETECTORS  
OEM DETECTORS  
SPECIAL PRODUCTS  
BEAM DIAGNOSTICS

# BEAMR2-BEAMMAP2



## SPECIFICATIONS

MODELS	BEAMR2	BEAMMAP2
SLIT-SCAN PLANES	XY	XYZ0Φ

### MEASUREMENT CAPABILITY

#### Dimensions of Capture Region

Si	4 mm
InGaAs	3 mm
Dual: Si + InGaAs	Si: 4 mm + InGaAs: 3 mm
Dual: Si + Extended InGaAs	Si: 4 mm + Extended InGaAs: 2 mm

#### Laser Types

CW or Pulsed

#### Waist Diameters ( $2\omega_0$ )

0.5 - 1500  $\mu\text{m}$

#### Waist Diameter Resolution

0.2 % of beam diameter

#### Best Resolution

0.1  $\mu\text{m}$

#### Precisions

Beam Divergence N/A  $\pm 1$  mrad over a  $\pm 100$  mrad range

Beam Pointing N/A  $\pm 1$  mrad over a  $\pm 100$  mrad range

Beam  $M^2$  N/A  $\pm < 5\%$ ,  $M^2 = 1.0$  to  $> 20$

#### Waist Centroid Position

$\pm 2$   $\mu\text{m}$  rms

#### Auto Gain Range

40 dB (10 000:1)

#### Update Rate

5 Hz

### WAVELENGTH RANGES

Si 190 - 1000 nm

InGaAs 650 - 1800 nm

Extended InGaAs 0.8 - 2.5  $\mu\text{m}$

### DAMAGE THRESHOLDS

Maximum Average Power 1 W

Maximum Irradiance 0.5 mW/ $\mu\text{m}^2$

### PHYSICAL CHARACTERISTICS

Dimensions 61.0H x 67.3W x 68.2D mm

Weight (head only) 450 g

Cable 3 m, USB 2.0, A to mini-B5

### ORDERING INFORMATION

#### Full Product Names

Si	BR2-Si	BMS2-4XY250*-Si
InGaAs	BR2-IGA	BMS2-4XY250*-IGA
Dual: Si + InGaAs	BR2-DD-2.0	BMS2-4XY250*-DD-2.0
Dual: Si + Extended InGaAs	BR2-DD-2.4	BMS2-4XY250*-DD-2.4

\* Default unit has 250  $\mu\text{m}$  plane spacing. 50, 100, 500, 750 & 5000  $\mu\text{m}$  plane spacings available

Specifications are subject to change without notice